Application No.:10/659,814 Docket No.: 29936/39462

## **AMENDMENTS TO THE SPECIFICATION**

On page 6, lines 16 to 21:

Turning to FIG. 4, an oxide film  $\frac{114}{113}$  for a spacer is deposited on the entire structure. It is preferable that a high temperature oxide (HTO) film using SiH<sub>2</sub>Cl<sub>2</sub> (dichlorosilane; DCS) is used as the oxide film  $\frac{114}{113}$  for the spacer. Further, it is preferred that the oxide film  $\frac{114}{113}$  for the spacer is deposited in  $\frac{114}{113}$  thickness of about  $400 \sim 1000$ Å at a temperature of about  $680 \sim 730$ °C.